WNSC5D30650CW

Silicon Carbide Diode

Rev.01 - 16 November 2022 Product data sheet

1. General description

Dual Silicon Carbide Schottky diode in a TO247 plastic package, designed for high frequency switched-mode power supplies.

RoHS Halogen-Free Lead-Free

2. Features and benefits

- Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

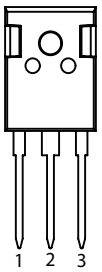
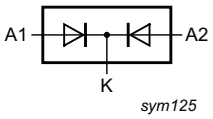
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V_{RRM}	repetitive peak reverse voltage			650			V
$I_{O(AV)}$	limiting average forward current	δ = 0.5 ; square-wave pulse; $T_{mb} \leq 101$ °C; both diodes conducting; Fig. 1; Fig. 2; Fig. 3		30			A
T_j	junction temperature			-55 to 175			°C
Symbol	**Parameter**	**Conditions**	**Notes**	**Min**	**Typ**	**Max**	**Unit**
Static characteristics							
V_F	forward voltage	I_F = 15 A; T_j = 25 °C; per diode; Fig. 5		-	1.45	1.70	V
		I_F = 15 A; T_j = 150 °C; per diode; Fig. 5		-	1.80	2.20	V
Dynamic characteristics							
Q_r	recovered charge	I_F = 15 A; dI_F/dt = 500 A/µs; V_R = 400 V; T_j = 25 °C; per diode; Fig. 7		-	24	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		
2	K	cathode		
3	A2	anode		
mb	mb	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC5D30650CW	TO247	WNSC5D30650CW6Q	Tube	30	TO247N	20-July-2016

7. Marking

Table 4. Marking codes

Type number	Marking codes
WNSC5D30650CW	WNSC5D 30650CW

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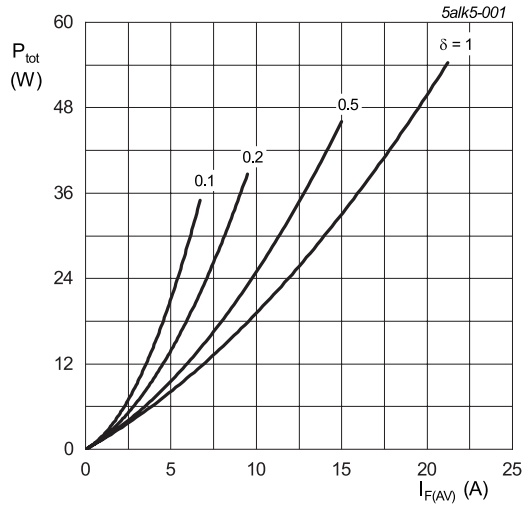
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
$I_{O(AV)}$	limiting average forward current	δ = 0.5; square-wave pulse; $T_{mb} \leq 101$ °C; both diodes conducting; Fig. 1; Fig. 2; Fig. 3		30	A
I_{FRM}	repetitive peak forward current	δ = 0.5; t_p = 25 µs; $T_{mb} \leq 111$ °C; square-wave pulse; per diode		30	A
I_{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		85	A
		t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse; per diode		800	A
I^2t	I^2t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; t_p = 10 ms		36.125	A^2s
T_{stg}	storage temperature			-55 to 175	°C
T_j	junction temperature			-55 to 175	°C



$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$

V_o = 1.334 V; R_s = 0.0578 Ω

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode

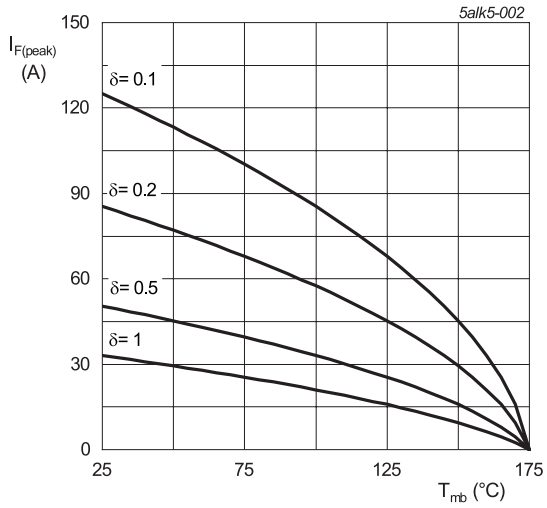


Fig. 2. Current derating as a function of mounting base temperature; per diode

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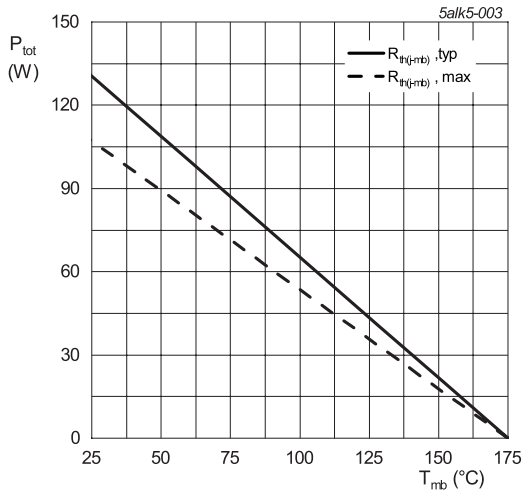

Fig. 3. Total power dissipation as a function of mounting base temperature; per diode

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	per diode; Fig. 4		-	1.15	1.4	K/W
		both diodes conducting		-	0.6	0.75	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

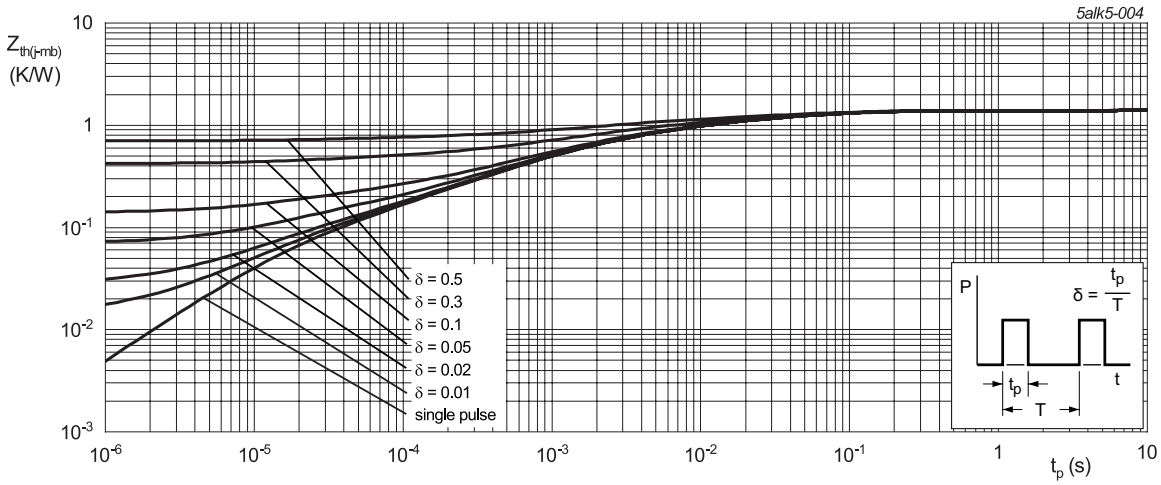

Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

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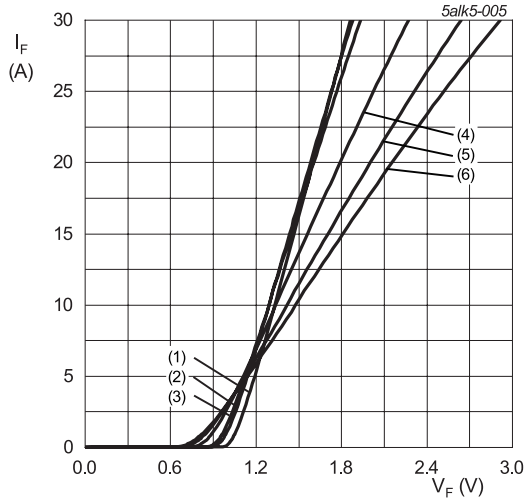
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V_F	forward current	I_F = 15 A; T_j = 25 °C; per diode; Fig. 5		-	1.45	1.70	V
		I_F = 15 A; T_j = 150 °C; per diode; Fig. 5		-	1.80	2.20	V
		I_F = 15 A; T_j = 175 °C; per diode; Fig. 5		-	2.00	2.30	V
I_R	reverse current	V_R = 650 V; T_j = 25 °C; per diode; Fig. 6		-	1	50	µA
		V_R = 650 V; T_j = 175 °C; per diode; Fig. 6		-	25	350	µA
Dynamic characteristics							
Q_r	recovered charge	I_F = 15 A; V_R = 400 V; dI_F/dt = 500 A/µs; T_j = 25 °C; per diode; Fig. 7		-	24	-	nC
C_d	diode capacitance	f = 1 MHz; V_R = 1 V; T_j = 25 °C; per diode		-	500	-	pF
		f = 1 MHz; V_R = 300 V; T_j = 25 °C; per diode		-	58	-	pF
		f = 1 MHz; V_R = 600 V; T_j = 25 °C; per diode		-	52	-	pF
E_{as}	non-repetitive avalanche energy	I_R = 5 A; L = 5 mH; $T_{j(init)}$ = 25 °C; per diode		60	-	-	mJ



V_o = 1.334 V; R_s = 0.0578 Ω
(1) T_j = -55 °C; typical values
(2) T_j = 0 °C; typical values
(3) T_j = 25 °C; typical values
(4) T_j = 100 °C; typical values
(5) T_j = 150 °C; typical values
(6) T_j = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values; per diode

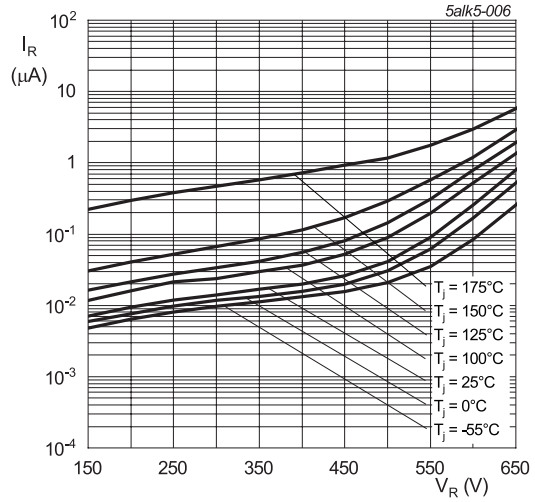


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value; per diode

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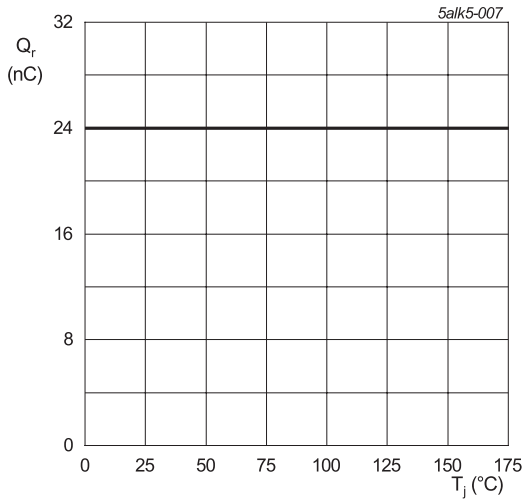

Fig. 7. Recovered charge as a function of junction temperature; per diode

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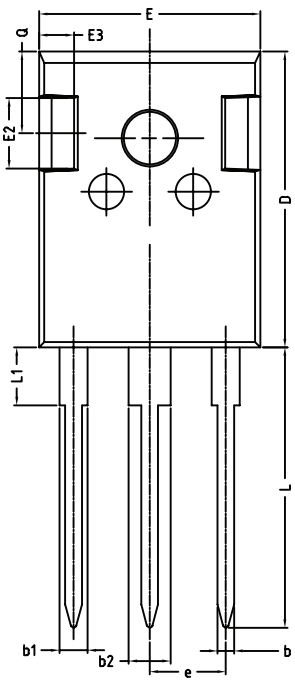
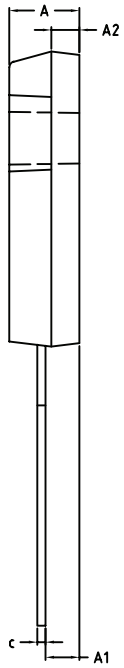
11. Package outline

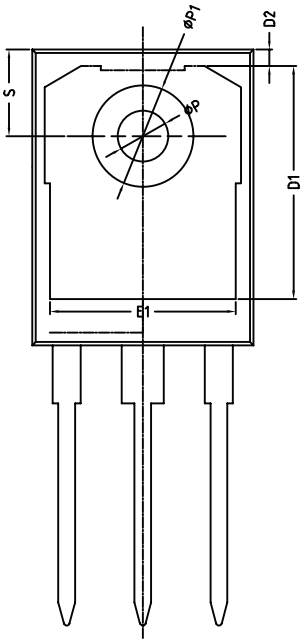
Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3-lead TO-247 SOT429N



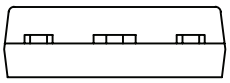
TOP VIEW



SIDE VIEW



BOTTOM VIEW



SIDE VIEW

UNIT		A	A1	A2	b	b1	b2	c	D	D1	D2	E	E1	E2	E3	e	L	L1	P	P1	Q	S
mm	MAX	5.20	2.60	2.10	1.40	2.20	3.20	0.70	21.10	16.85	1.35	15.90	13.50	5.20	2.60	5.45	20.10	4.75	3.70	7.40	6.00	6.25
	NOM																					
	MIN	4.70	2.20	1.90	1.00	1.80	2.80	0.50	20.90	16.25	1.05	15.70	13.10	4.80	2.40		19.80	–	3.50	–	5.60	6.05

OUTLINE VERSION	REFERENCES				PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT429N		TO-247				

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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